

NCP45524, NCP45525

ecoSWITCH™ Advanced Load Management Controlled Load Switch with Low R_{ON}

The NCP4552x series of load switches provide a component and area-reducing solution for efficient power domain switching with inrush current limit via soft start. These devices are designed to integrate control and driver functionality with a high performance low on-resistance power MOSFET in a single package. This cost effective solution is ideal for power management and hot-swap applications requiring low power consumption in a small footprint.

Features

- Advanced Controller with Charge Pump
- Integrated N-Channel MOSFET with Low R_{ON}
- Input Voltage Range 0.5 V to 13.5 V
- Soft-Start via Controlled Slew Rate
- Adjustable Slew Rate Control (NCP45525)
- Power Good Signal (NCP45524)
- Extremely Low Standby Current
- Load Bleed (Quick Discharge)
- This is a Pb-Free Device

Typical Applications

- Portable Electronics and Systems
- Notebook and Tablet Computers
- Telecom, Networking, Medical, and Industrial Equipment
- Set-Top Boxes, Servers, and Gateways
- Hot Swap Devices and Peripheral Ports

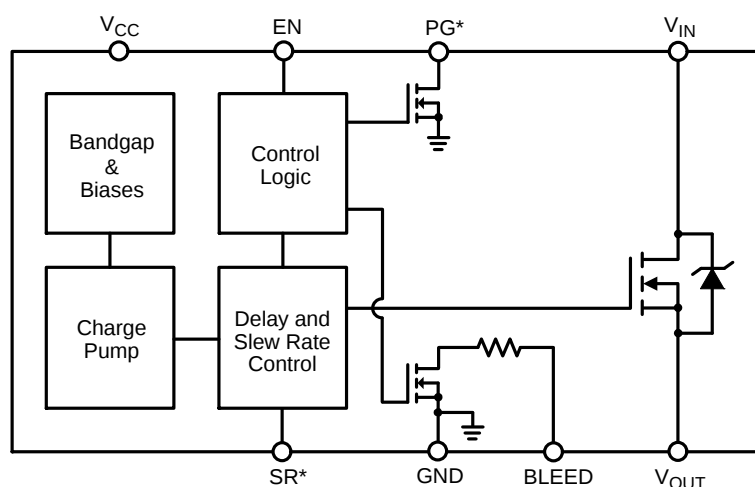


Figure 1. Block Diagram

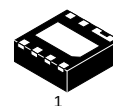
(*Note: either PG or SR available for each part)



ON Semiconductor®

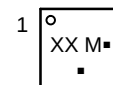
<http://onsemi.com>

R_{ON} TYP	V_{CC}	V_{IN}	I_{MAX}
18.0 mΩ	3.3 V	1.8 V	6 A
18.8 mΩ	3.3 V	5.0 V	
21.9 mΩ	3.3 V	12 V	



DFN8, 2x2
CASE 506CC

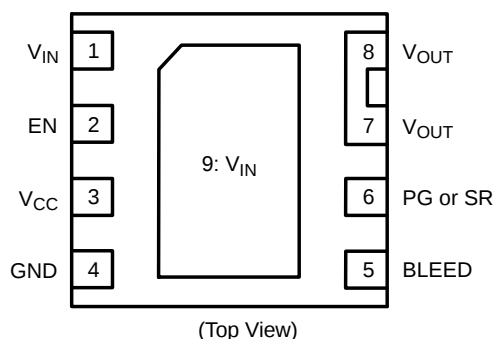
MARKING DIAGRAM



XX = 4H for NCP45524-H
 = 4L for NCP45524-L
 = 5H for NCP45525-H
 = 5L for NCP45525-L
 M = Date Code
 ■ = Pb-Free Package

(Note: Microdot may be in either location)

PIN CONFIGURATION



(Top View)

ORDERING INFORMATION

See detailed ordering and shipping information on page 14 of this data sheet.

NCP45524, NCP45525

Table 1. PIN DESCRIPTION

Pin	Name	Function
1, 9	V _{IN}	Drain of MOSFET (0.5 V – 13.5 V), Pin 1 must be connected to Pin 9
2	EN	NCP45524-H & NCP45525-H – Active-high digital input used to turn on the MOSFET, pin has an internal pull down resistor to GND
		NCP45524-L & NCP45525-L – Active-low digital input used to turn on the MOSFET, pin has an internal pull up resistor to V _{CC}
3	V _{CC}	Supply voltage to controller (3.0 V – 5.5 V)
4	GND	Controller ground
5	BLEED	Load bleed connection; must be tied to V _{OUT} either directly or through a resistor ≤ 100 MΩ.
6	PG	NCP45524 – Active-high, open-drain output that indicates when the gate of the MOSFET is fully charged, external pull up resistor ≥ 1 kΩ to an external voltage source required; tie to GND if not used
	SR	NCP45525 – Slew rate adjustment; float if not used
7, 8	V _{OUT}	Source of MOSFET connected to load

Table 2. ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Supply Voltage Range	V _{CC}	–0.3 to 6	V
Input Voltage Range	V _{IN}	–0.3 to 18	V
Output Voltage Range	V _{OUT}	–0.3 to 18	V
EN Digital Input Range	V _{EN}	–0.3 to (V _{CC} + 0.3)	V
PG Output Voltage Range (Note 1)	V _{PG}	–0.3 to 6	V
Thermal Resistance, Junction-to-Ambient, Steady State (Note 2)	R _{θJA}	40.0	°C/W
Thermal Resistance, Junction-to-Ambient, Steady State (Note 3)	R _{θJA}	72.7	°C/W
Thermal Resistance, Junction-to-Case (V _{IN} Paddle)	R _{θJC}	5.3	°C/W
Continuous MOSFET Current @ T _A = 25°C	I _{MAX}	6.0	A
Total Power Dissipation @ T _A = 25°C (Notes 2 and 4) Derate above T _A = 25°C	P _D	2.50 24.9	W mW/°C
Total Power Dissipation @ T _A = 25°C (Notes 3 and 4) Derate above T _A = 25°C	P _D	1.37 13.8	W mW/°C
Storage Temperature Range	T _{STG}	–40 to 150	°C
Lead Temperature, Soldering (10 sec.)	T _{SLD}	260	°C
ESD Capability, Human Body Model (Notes 5 and 6)	ESD _{HBM}	3.0	kV
ESD Capability, Machine Model (Note 5)	ESD _{MM}	200	V
ESD Capability, Charged Device Model (Note 5)	ESD _{CDM}	1.0	kV
Latch-up Current Immunity (Notes 5 and 6)	LU	100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. NCP45524 only. PG is an open-drain output that requires an external pull up resistor ≥ 1 kΩ to an external voltage source.
2. Surface-mounted on FR4 board using 1 sq-in pad, 1 oz Cu.
3. Surface-mounted on FR4 board using the minimum recommended pad size, 1 oz Cu.
4. Specified for derating purposes only, ensure that I_{MAX} is never exceeded.
5. Tested by the following methods @ T_A = 25°C:
 ESD Human Body Model tested per JESD22-A114
 ESD Machine Model tested per JESD22-A115
 ESD Charged Device Model tested per JESD22-C101
 Latch-up Current tested per JESD78
6. Rating is for all pins except for V_{IN} and V_{OUT} which are tied to the internal MOSFET's Drain and Source. Typical MOSFET ESD performance for V_{IN} and V_{OUT} should be expected and these devices should be treated as ESD sensitive.

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Table 3. OPERATING RANGES

Rating	Symbol	Min	Max	Unit
Supply Voltage	V_{CC}	3	5.5	V
Input Voltage	V_{IN}	0.5	13.5	V
Ground	GND		0	V
Ambient Temperature	T_A	-40	85	°C
Junction Temperature	T_J	-40	125	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

Table 4. ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Conditions (Note 7)	Symbol	Min	Typ	Max	Unit
MOSFET						
On-Resistance	$V_{CC} = 3.3\text{ V}; V_{IN} = 1.8\text{ V}$	R_{ON}		18.0	24.0	mΩ
	$V_{CC} = 3.3\text{ V}; V_{IN} = 5\text{ V}$			18.8	25.0	
	$V_{CC} = 3.3\text{ V}; V_{IN} = 12\text{ V}$			21.9	31.7	
Leakage Current (Note 8)	$V_{EN} = 0\text{ V}; V_{IN} = 13.5\text{ V}$	I_{LEAK}		0.1	1	μA
CONTROLLER						
Supply Standby Current (Note 9)	$V_{EN} = 0\text{ V}; V_{CC} = 3\text{ V}$	I_{STBY}		0.65	2	μA
	$V_{EN} = 0\text{ V}; V_{CC} = 5.5\text{ V}$			3.2	4.5	
Supply Dynamic Current (Note 10)	$V_{EN} = V_{CC} = 3\text{ V}; V_{IN} = 12\text{ V}$	I_{DYN}		180	300	μA
	$V_{EN} = V_{CC} = 5.5\text{ V}; V_{IN} = 1.8\text{ V}$			475	680	
Bleed Resistance	$V_{EN} = 0\text{ V}; V_{CC} = 3\text{ V}$	R_{BLEED}	86	115	144	Ω
	$V_{EN} = 0\text{ V}; V_{CC} = 5.5\text{ V}$		72	97	121	
EN Input High Voltage	$V_{CC} = 3\text{ V} - 5.5\text{ V}$	V_{IH}	2			V
EN Input Low Voltage	$V_{CC} = 3\text{ V} - 5.5\text{ V}$	V_{IL}			0.8	V
EN Input Leakage Current	NCP45524-H; NCP45525-H; $V_{EN} = 0\text{ V}$	I_{IL}		90	500	nA
	NCP45524-L; NCP45525-L; $V_{EN} = 5.5\text{ V}$	I_{IH}		90	500	
EN Pull Down Resistance	NCP45524-H; NCP45525-H	R_{PD}	76	100	124	kΩ
EN Pull Up Resistance	NCP45524-L; NCP45525-L	R_{PU}	76	100	124	kΩ
PG Output Low Voltage (Note 11)	NCP45524; $V_{CC} = 3\text{ V}; I_{SINK} = 5\text{ mA}$	V_{OL}			0.2	V
PG Output Leakage Current (Note 12)	NCP45524; $V_{CC} = 3\text{ V}; V_{TERM} = 3.3\text{ V}$	I_{OH}		5	100	nA
Slew Rate Control Constant (Note 13)	NCP45525; $V_{CC} = 3\text{ V}$	K_{SR}	24	31	38	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

7. V_{EN} shown only for NCP45524-H, NCP45525-H (EN Active-High) unless otherwise specified.

8. Average current from V_{IN} to V_{OUT} with MOSFET turned off.

9. Average current from V_{CC} to GND with MOSFET turned off.

10. Average current from V_{CC} to GND after charge up time of MOSFET.

11. PG is an open-drain output that is pulled low when the MOSFET is disabled.

12. PG is an open-drain output that is not driven when the gate of the MOSFET is fully charged, requires an external pull up resistor $\geq 1\text{ k}\Omega$ to an external voltage source, V_{TERM} .

13. See Applications Information section for details on how to adjust the slew rate.

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Table 5. SWITCHING CHARACTERISTICS ($T_J = 25^\circ\text{C}$ unless otherwise specified) (Notes 14 and 15)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Output Slew Rate (Note 16)	$V_{CC} = 3.3\text{ V}; V_{IN} = 1.8\text{ V}$	SR		11.9		kV/s
	$V_{CC} = 5.0\text{ V}; V_{IN} = 1.8\text{ V}$			12.1		
	$V_{CC} = 3.3\text{ V}; V_{IN} = 12\text{ V}$			13.5		
	$V_{CC} = 5.0\text{ V}; V_{IN} = 12\text{ V}$			13.9		
Output Turn-on Delay (Note 16)	$V_{CC} = 3.3\text{ V}; V_{IN} = 1.8\text{ V}$	T_{ON}		220		μs
	$V_{CC} = 5.0\text{ V}; V_{IN} = 1.8\text{ V}$			185		
	$V_{CC} = 3.3\text{ V}; V_{IN} = 12\text{ V}$			270		
	$V_{CC} = 5.0\text{ V}; V_{IN} = 12\text{ V}$			260		
Output Turn-off Delay (Note 16)	$V_{CC} = 3.3\text{ V}; V_{IN} = 1.8\text{ V}$	T_{OFF}		1.2		μs
	$V_{CC} = 5.0\text{ V}; V_{IN} = 1.8\text{ V}$			0.9		
	$V_{CC} = 3.3\text{ V}; V_{IN} = 12\text{ V}$			0.4		
	$V_{CC} = 5.0\text{ V}; V_{IN} = 12\text{ V}$			0.2		
Power Good Turn-on Time (Note 17)	$V_{CC} = 3.3\text{ V}; V_{IN} = 1.8\text{ V}$	$T_{PG,ON}$		0.91		ms
	$V_{CC} = 5.0\text{ V}; V_{IN} = 1.8\text{ V}$			0.93		
	$V_{CC} = 3.3\text{ V}; V_{IN} = 12\text{ V}$			1.33		
	$V_{CC} = 5.0\text{ V}; V_{IN} = 12\text{ V}$			1.21		
Power Good Turn-off Time (Note 17)	$V_{CC} = 3.3\text{ V}; V_{IN} = 1.8\text{ V}$	$T_{PG,OFF}$		21		ns
	$V_{CC} = 5.0\text{ V}; V_{IN} = 1.8\text{ V}$			15		
	$V_{CC} = 3.3\text{ V}; V_{IN} = 12\text{ V}$			21		
	$V_{CC} = 5.0\text{ V}; V_{IN} = 12\text{ V}$			15		

14. See below figure for Test Circuit and Timing Diagram.

15. Tested with the following conditions: $V_{TERM} = V_{CC}$; $R_{PG} = 100\text{ k}\Omega$; $R_L = 10\text{ }\Omega$; $C_L = 0.1\text{ }\mu\text{F}$.

16. Applies to NCP45524 and NCP45525.

17. Applies only to NCP45524.

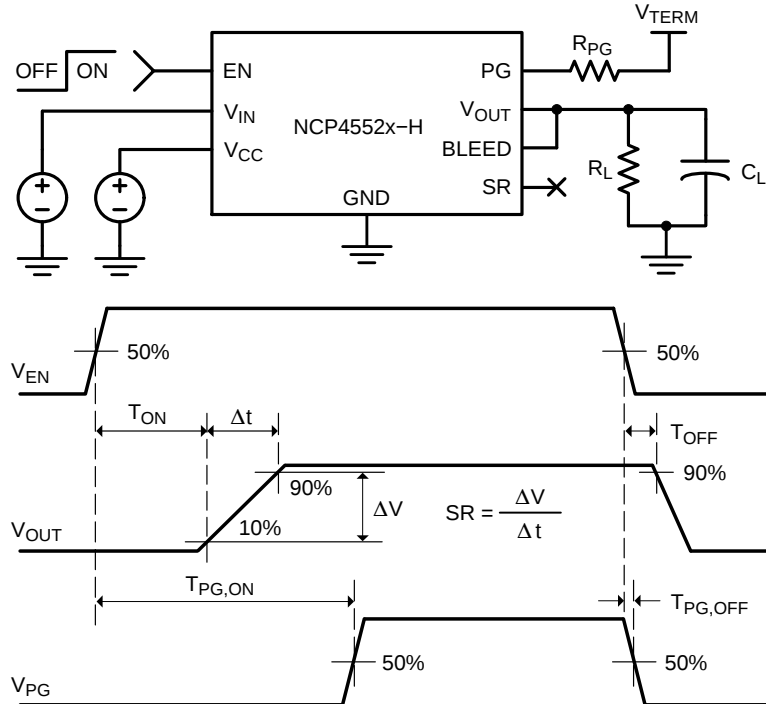


Figure 2. Switching Characteristics Test Circuit and Timing Diagram

TYPICAL CHARACTERISTICS

($T_J = 25^\circ\text{C}$ unless otherwise specified)

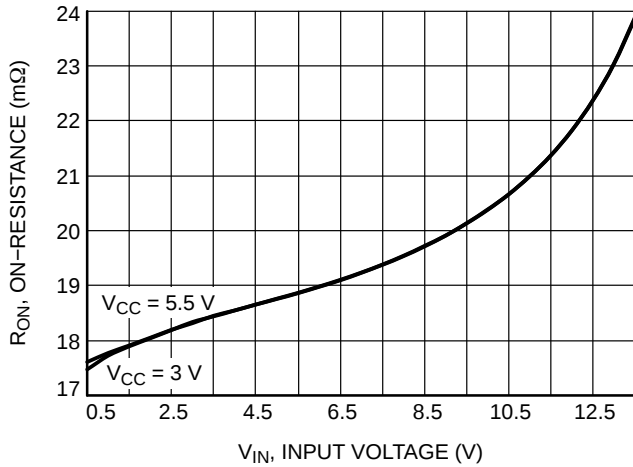


Figure 3. On-Resistance vs. Input Voltage

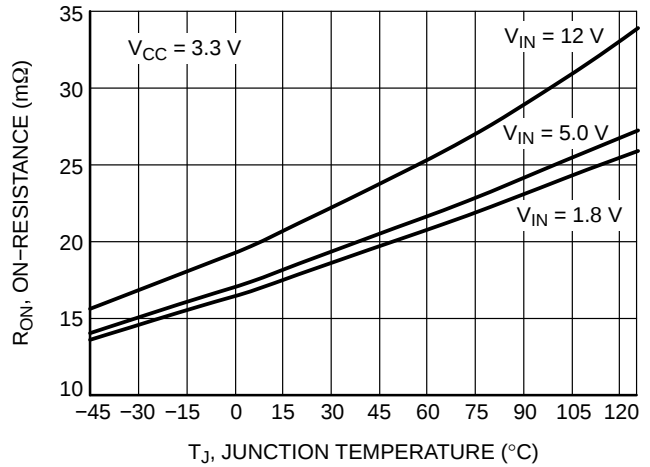


Figure 4. On-Resistance vs. Temperature

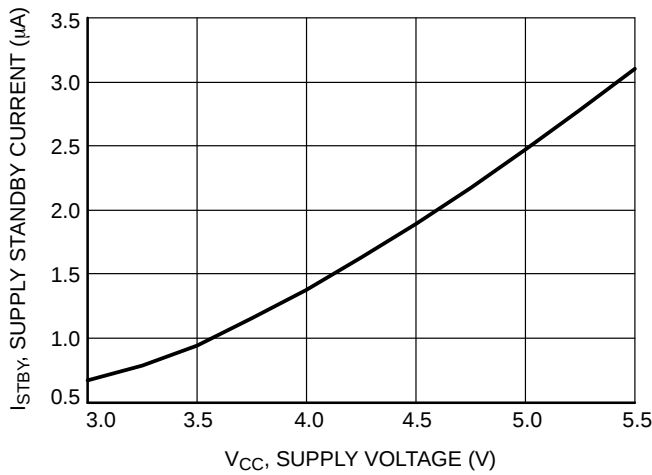


Figure 5. Supply Standby Current vs. Supply Voltage

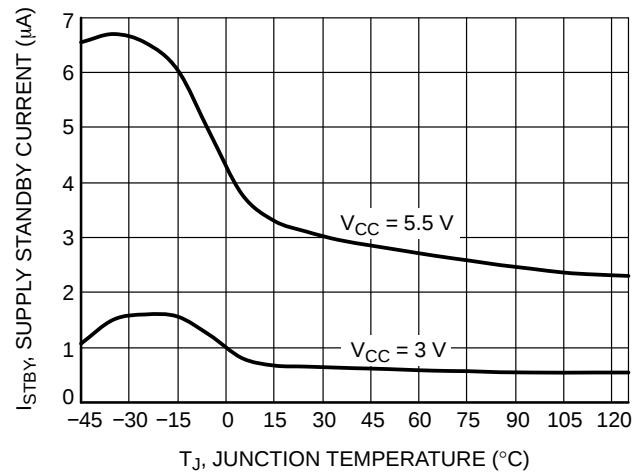


Figure 6. Supply Standby Current vs. Temperature

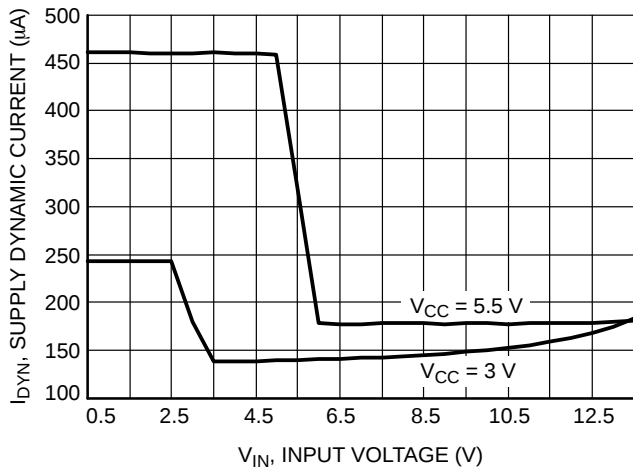


Figure 7. Supply Dynamic Current vs. Input Voltage

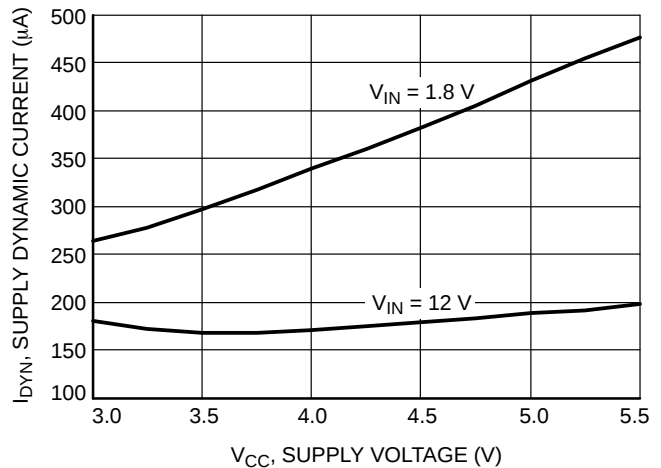


Figure 8. Supply Dynamic Current vs. Supply Voltage

TYPICAL CHARACTERISTICS

($T_J = 25^\circ\text{C}$ unless otherwise specified)

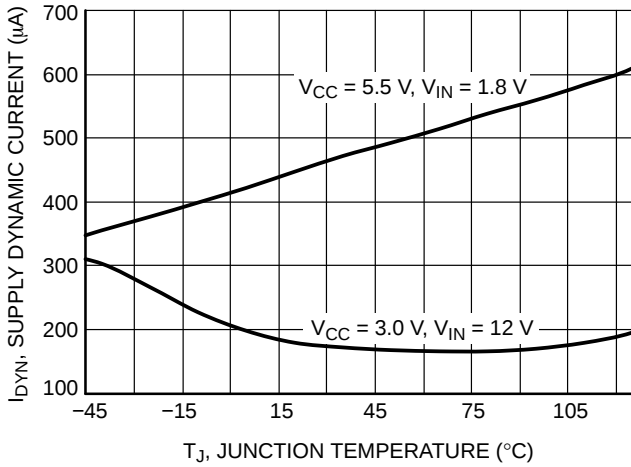


Figure 9. Supply Dynamic Current vs. Temperature

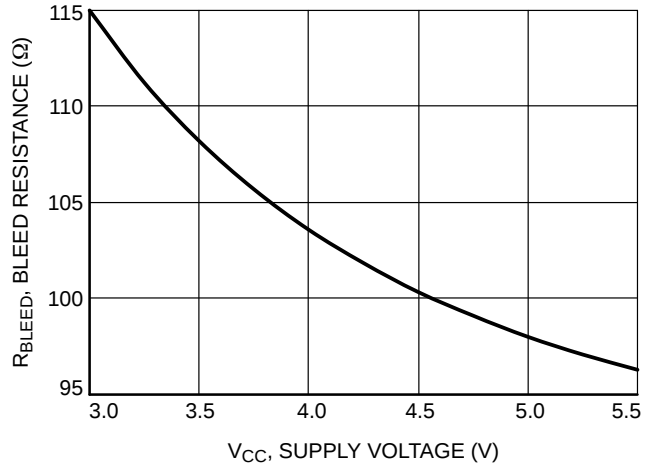


Figure 10. Bleed Resistance vs. Supply Voltage

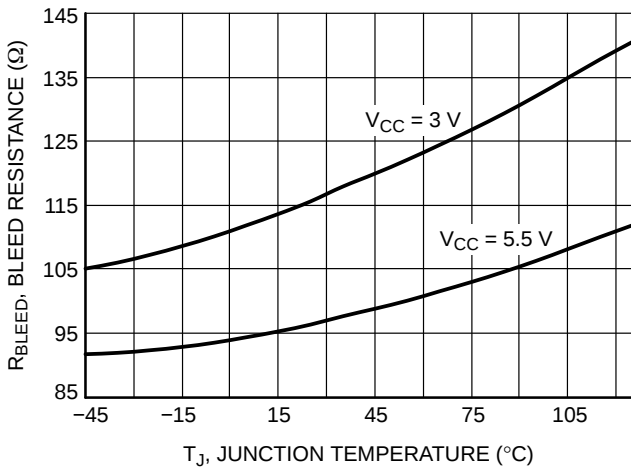


Figure 11. Bleed Resistance vs. Temperature

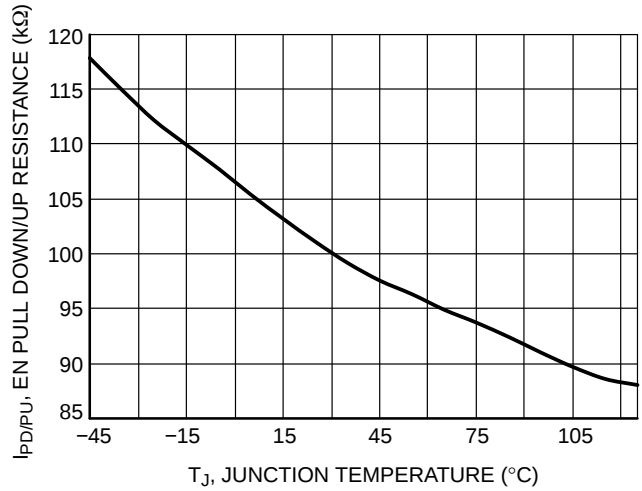


Figure 12. EN Pull Down/Up Resistance vs. Temperature

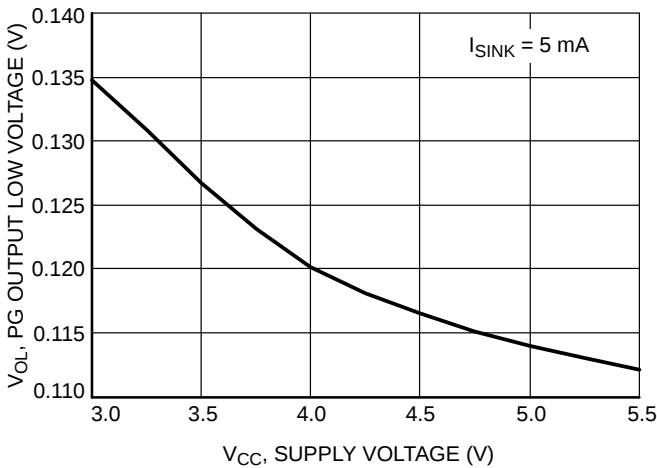


Figure 13. PG Output Low Voltage vs. Supply Voltage

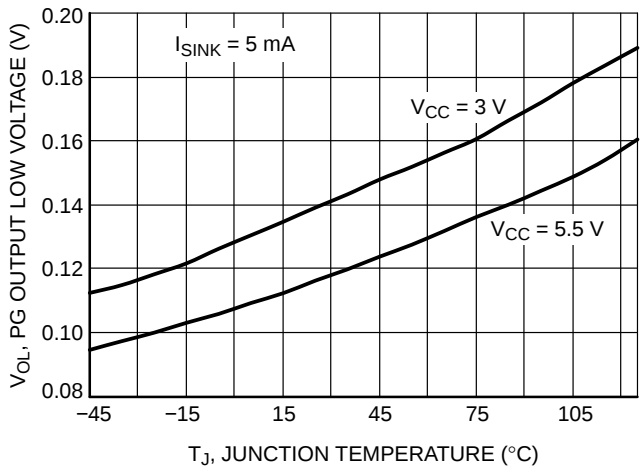


Figure 14. PG Output Low Voltage vs. Temperature

TYPICAL CHARACTERISTICS

($T_J = 25^\circ\text{C}$ unless otherwise specified)

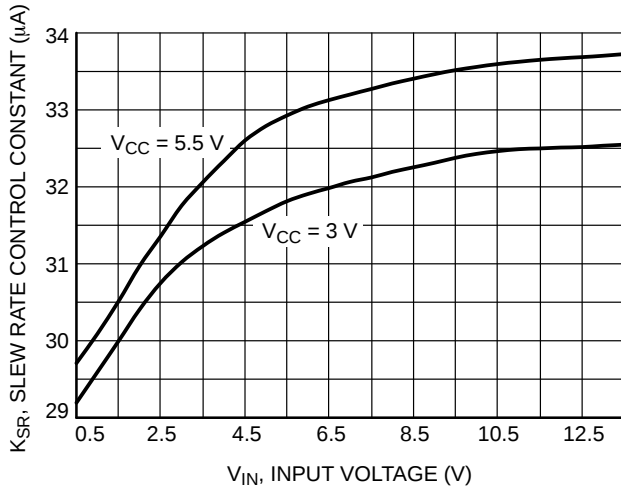


Figure 15. Slew Rate Control Constant vs. Input Voltage

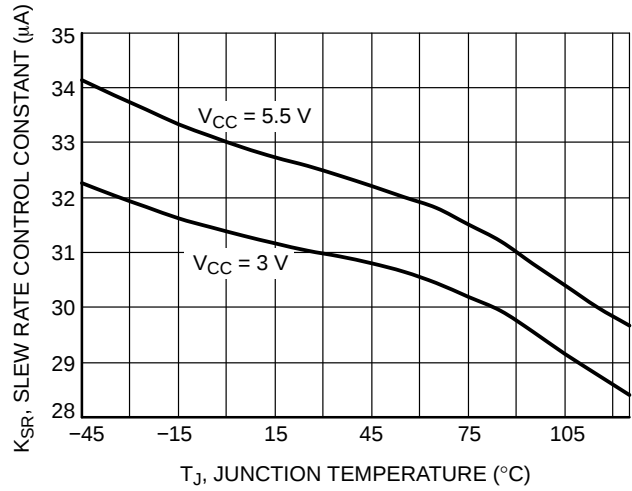


Figure 16. Slew Rate Control Constant vs. Temperature

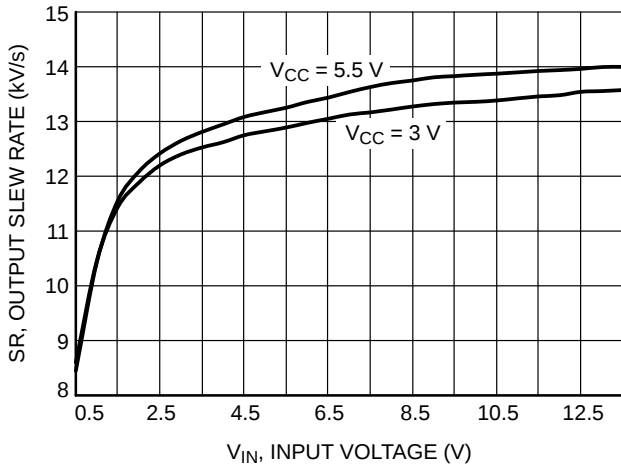


Figure 17. Output Slew Rate vs. Input Voltage

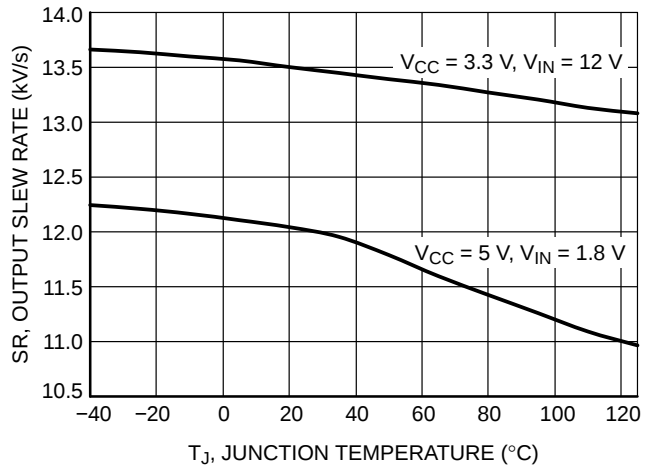


Figure 18. Output Slew Rate vs. Temperature

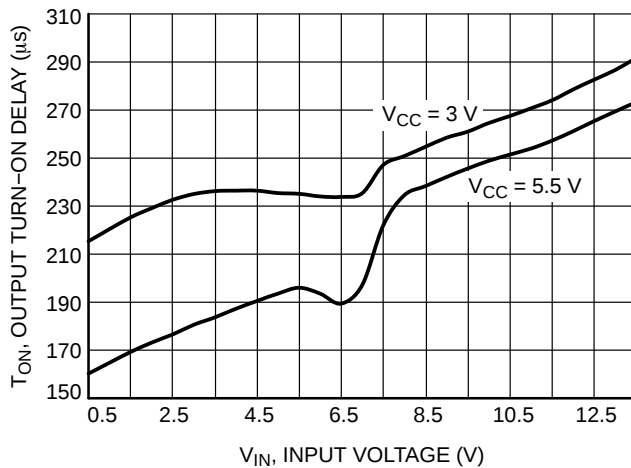


Figure 19. Output Turn-on Delay vs. Input Voltage

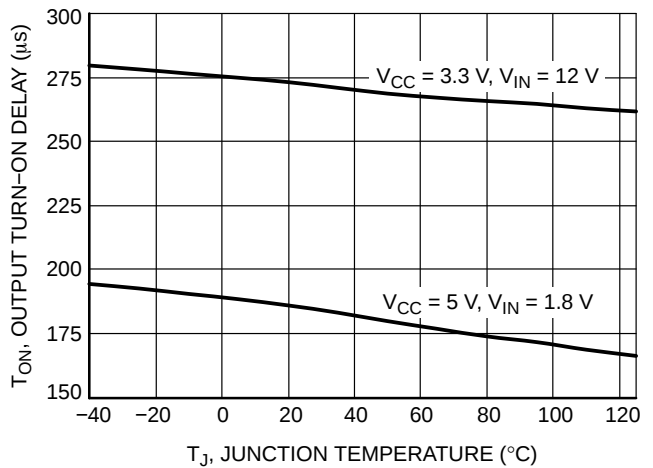


Figure 20. Output Turn-on Delay vs. Temperature

TYPICAL CHARACTERISTICS

($T_J = 25^\circ\text{C}$ unless otherwise specified)

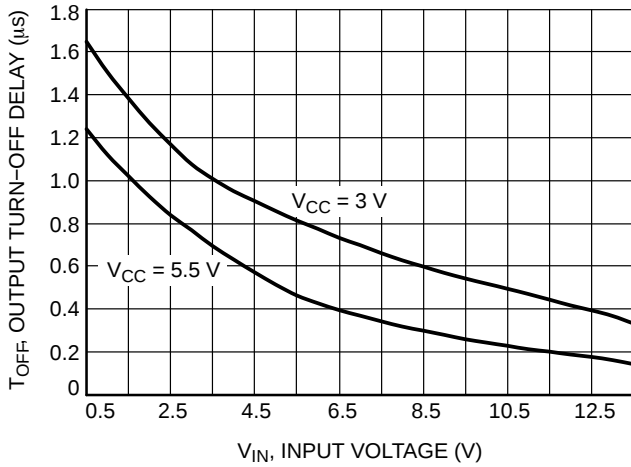


Figure 21. Output Turn-off Delay vs. Input Voltage

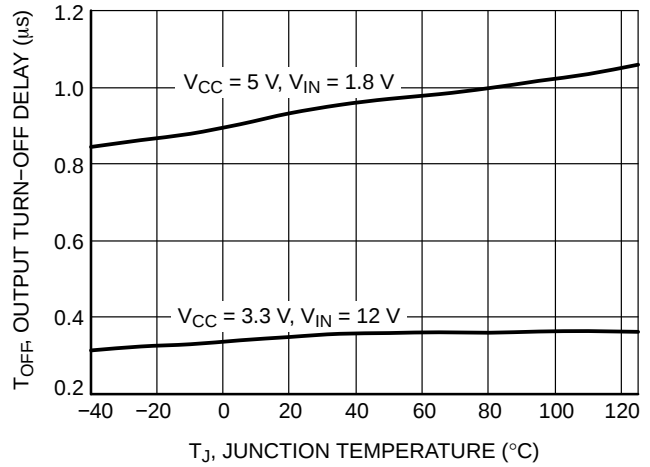


Figure 22. Output Turn-off Delay vs. Temperature

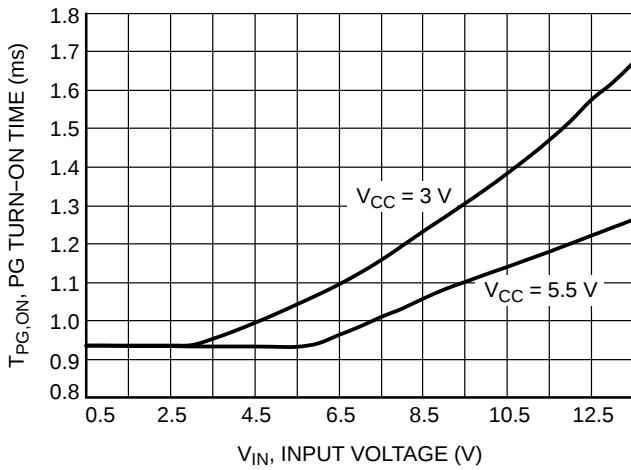


Figure 23. Power Good Turn-on Time vs. Input Voltage

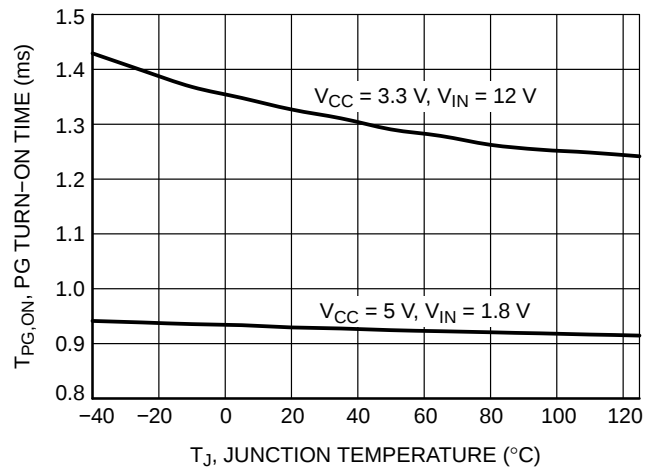


Figure 24. Power Good Turn-on Time vs. Temperature

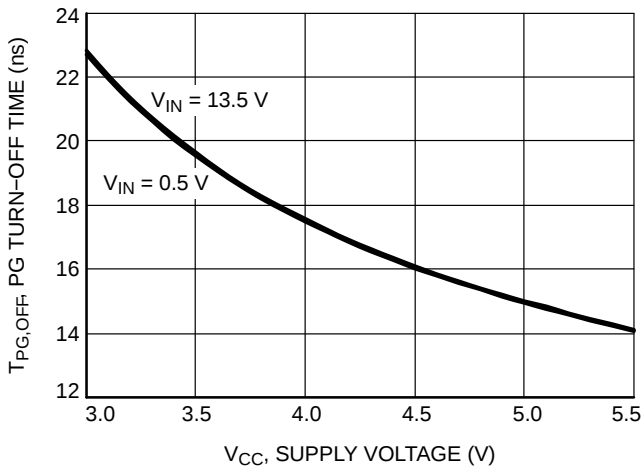


Figure 25. Power Good Turn-off Time vs. Supply Voltage

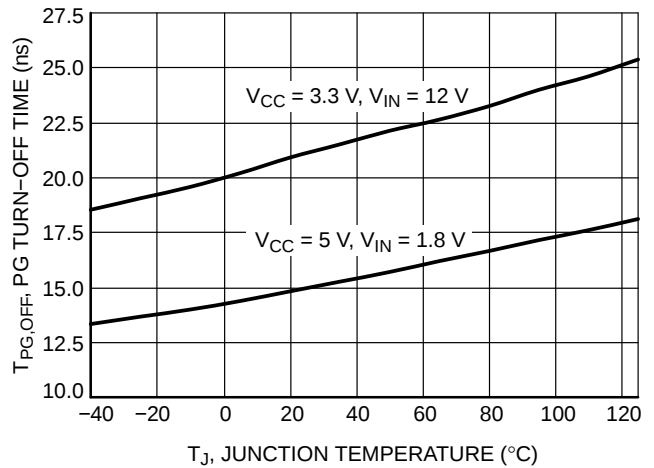


Figure 26. Power Good Turn-off Time vs. Temperature

APPLICATIONS INFORMATION

Enable Control

Both the NCP45524 and the NCP45525 have two part numbers, NCP4552x-H and NCP4552x-L, that only differ in the polarity of the enable control.

The NCP4552x-H devices allow for enabling the MOSFET in an active-high configuration. When the V_{CC} supply pin has an adequate voltage applied and the EN pin is at a logic high level, the MOSFET will be enabled. Similarly, when the EN pin is at a logic low level, the MOSFET will be disabled. An internal pull down resistor to ground on the EN pin ensures that the MOSFET will be disabled when not being driven.

The NCP4552x-L devices allow for enabling the MOSFET in an active-low configuration. When the V_{CC} supply pin has an adequate voltage applied and the EN pin is at a logic low level, the MOSFET will be enabled. Similarly, when the EN pin is at a logic high level, the MOSFET will be disabled. An internal pull up resistor to V_{CC} on the EN pin ensures that the MOSFET will be disabled when not being driven.

Power Sequencing

The NCP4552x devices will function with any power sequence, but the output turn-on delay performance may vary from what is specified. To achieve the specified performance, there are two recommended power sequences:

- 1) $V_{CC} \rightarrow V_{IN} \rightarrow V_{EN}$
- 2) $V_{IN} \rightarrow V_{CC} \rightarrow V_{EN}$

Load Bleed (Quick Discharge)

The NCP4552x devices have an internal bleed resistor, R_{BLEED} , which is used to bleed the charge off of the load to ground after the MOSFET has been disabled. In series with the bleed resistor is a bleed switch that is enabled whenever the MOSFET is disabled. The MOSFET and the bleed switch are never concurrently active.

Is it required that the BLEED pin be connected to V_{OUT} either directly (as shown in Figures 28 and 31) or through an external resistor, R_{EXT} (as shown in Figures 27 and 30). R_{EXT} should not exceed 100 M Ω and can be used to increase the total bleed resistance and decrease the load bleed rate.

Care must be taken to ensure that the power dissipated across R_{BLEED} is kept at a safe level. The maximum

continuous power that can be dissipated across R_{BLEED} is 0.4 W. R_{EXT} can be used to decrease the amount of power dissipated across R_{BLEED} .

Power Good

The NCP45524 devices have a power good output (PG) that can be used to indicate when the gate of the MOSFET is fully charged. The PG pin is an active-high, open-drain output that requires an external pull up resistor, R_{PG} , greater than or equal to 1 k Ω to an external voltage source, V_{TERM} , that is compatible with input levels of all devices connected to this pin (as shown in Figures 27 and 28).

The power good output can be used as the enable signal for other active-high devices in the system (as shown in Figure 29). This allows for guaranteed by design power sequencing and reduces the number of enable signals needed from the system controller. If the power good feature is not used in the application, the PG pin should be tied to GND.

Slew Rate Control

The NCP4552x devices are equipped with controlled output slew rate which provides soft start functionality. This limits the inrush current caused by capacitor charging and enables these devices to be used in hot swap applications.

The slew rate of the NCP45525 can be decreased with an external capacitor added between the SR pin and ground (as shown in Figures 30 and 31). With an external capacitor present, the slew rate can be determined by the following equation:

$$\text{Slew Rate} = \frac{K_{SR}}{C_{SR}} \text{ [V/s]} \quad (\text{eq. 1})$$

where K_{SR} is the specified slew rate control constant, found in Table 4, and C_{SR} is the slew rate control capacitor added between the SR pin and ground. The slew rate of the device will always be the lower of the default slew rate and the adjusted slew rate. Therefore, if the C_{SR} is not large enough to decrease the slew rate more than the specified default value, the slew rate of the device will be the default value. The SR pin can be left floating if the slew rate does not need to be decreased.

NCP45524, NCP45525

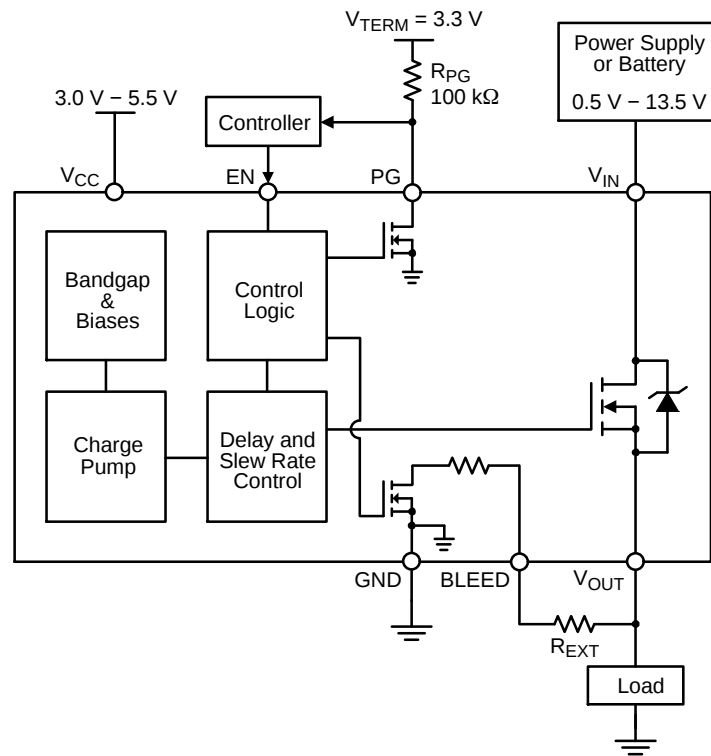


Figure 27. NCP45524 Typical Application Diagram – Load Switch

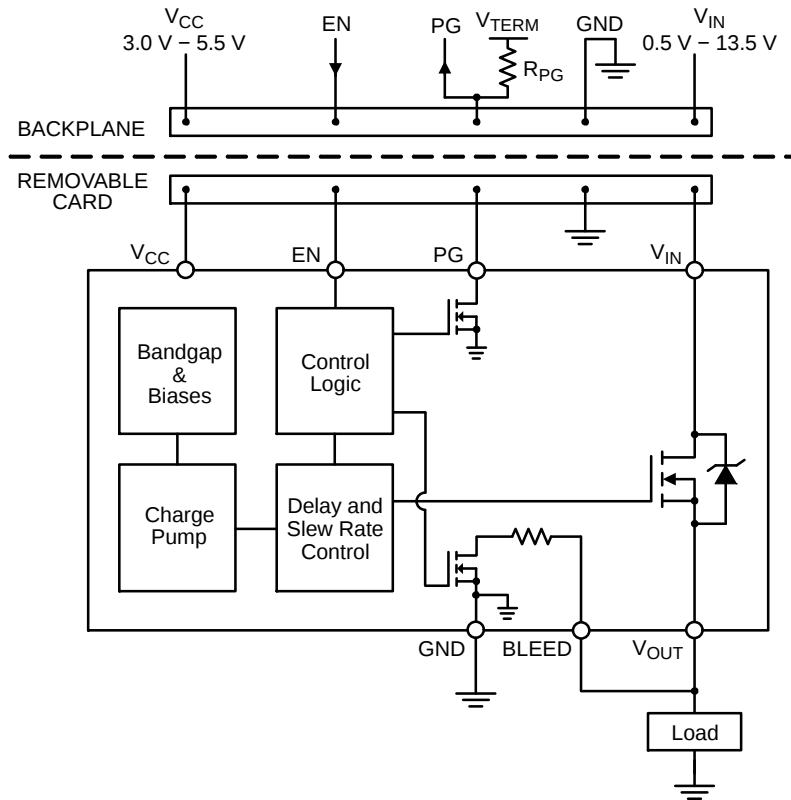


Figure 28. NCP45524 Typical Application Diagram – Hot Swap

NCP45524, NCP45525

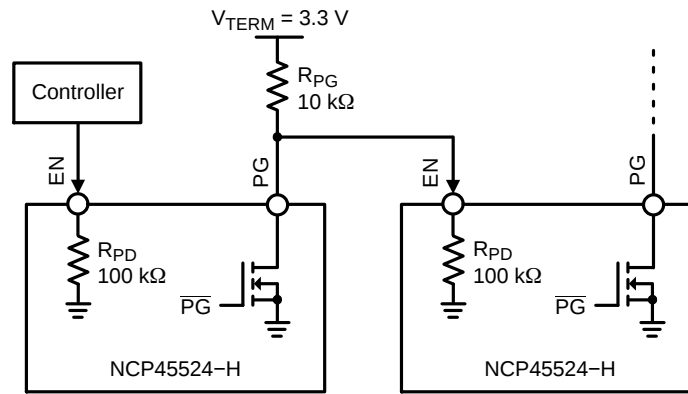


Figure 29. NCP45524 Simplified Application Diagram – Power Sequencing with PG Output

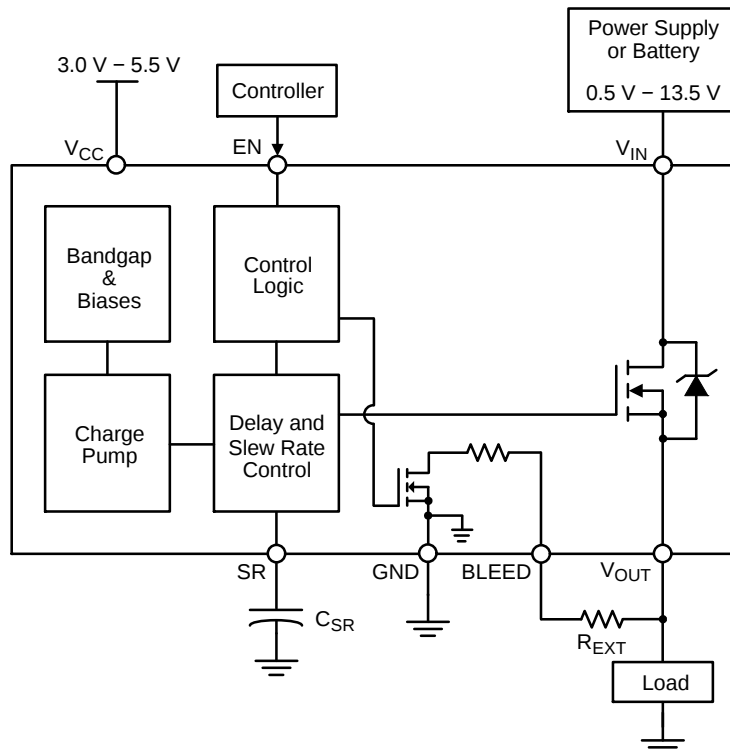


Figure 30. NCP45525 Typical Application Diagram – Load Switch

NCP45524, NCP45525

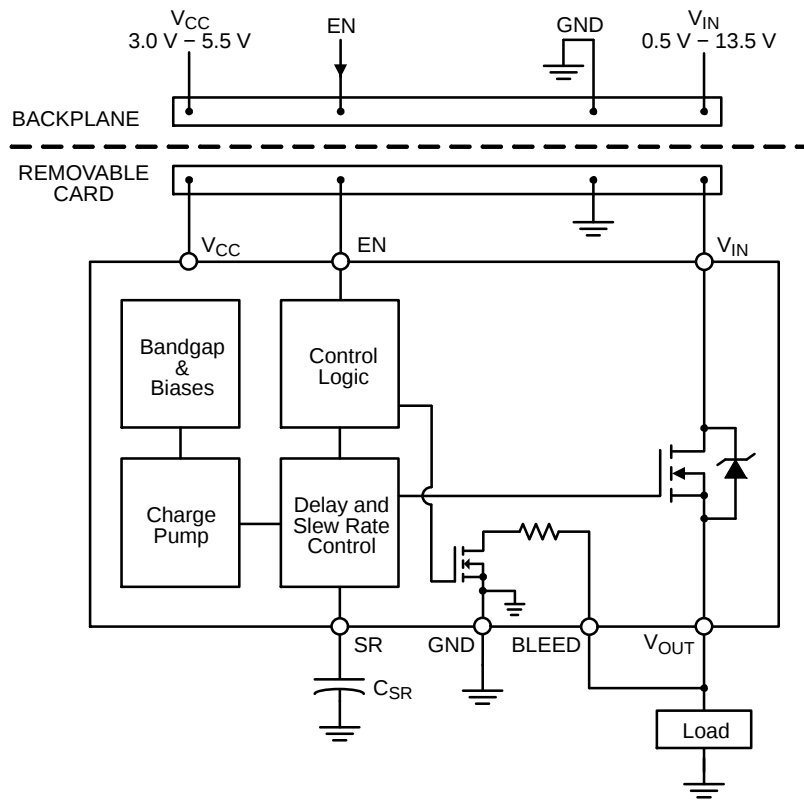
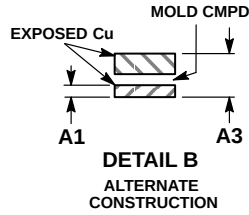
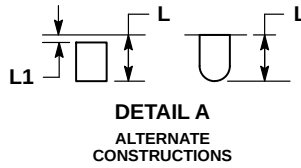
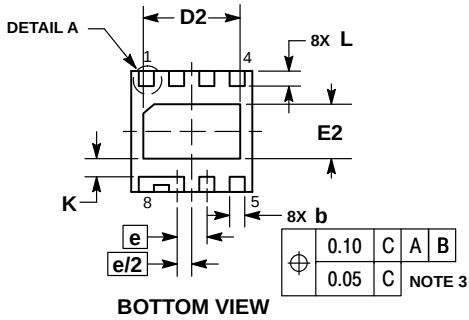
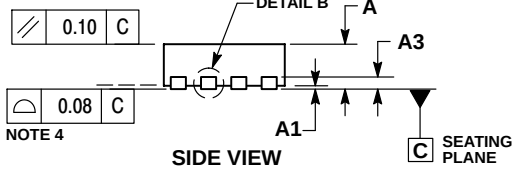
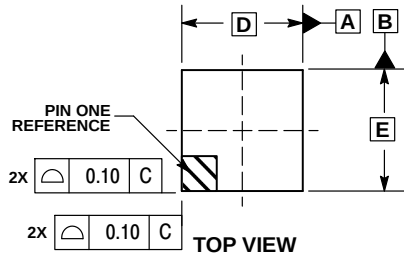


Figure 31. NCP45525 Typical Application Diagram – Hot Swap

NCP45524, NCP45525

PACKAGE DIMENSIONS

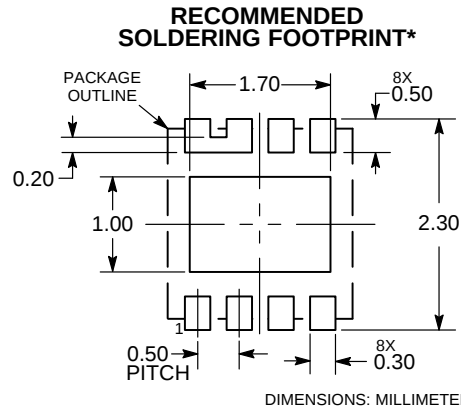
DFN8 2x2, 0.5P
CASE 506CC
ISSUE O



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 MM FROM TERMINAL TIP.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

MILLIMETERS		
DIM	MIN	MAX
A	0.80	1.00
A1	0.00	0.05
A3	0.20	REF
b	0.20	0.30
D	2.00	BSC
D2	1.50	1.70
E	2.00	BSC
E2	0.80	1.00
e	0.50	BSC
K	0.27	REF
L	0.18	0.38
L1	---	0.15



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NCP45524, NCP45525

ORDERING INFORMATION

Device	Pin 6 Functionality	EN Polarity	Package	Shipping [†]
NCP45524IMNTWG-H	PG	Active-High	DFN8 (Pb-Free)	3000 / Tape & Reel
NCP45524IMNTWG-L	PG	Active-Low		
NCP45525IMNTWG-H	SR	Active-High		
NCP45525IMNTWG-L	SR	Active-Low		

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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